

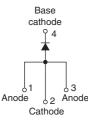
Vishay Semiconductors

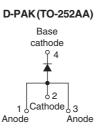
High Performance Generation 5.0 Schottky Rectifier, 10 A





I-PAK(TO-251AA)





VS-10UT10

VS-10WT10FN

PRODUCT SUMMARY				
Declara	I-PAK (TO-251AA),			
Package	D-PAK (TO-252AA)			
I _{F(AV)}	10 A			
V _R	100 V			
V _F at I _F	0.66 V			
I _{RM} max.	4 mA at 125 °C			
T _J max.	175 °C			
Diode variation	Single die			
E _{AS}	54 mJ			

FEATURES

- 175 °C high performance Schottky diode
- Very low forward voltage drop
- · Extremely low reverse leakage
- Optimized V_F vs. I_B trade off for high efficiency
- Increased ruggedness for reverse avalanche capability
- RBSOA available
- Negligible switching losses
- Submicron trench technology
- Compliant to RoHS Directive 2002/95/EC
- Designed and gualified according to JEDEC-JESD47

APPLICATIONS

- High efficiency SMPS
- High frequency switching
- Output rectification
- Reverse battery protection
- Freewheeling
- DC/DC systems
- · Increased power density systems

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
V _{RRM}		100	V			
V _F	10 Apk, T _J = 125 °C (typical)	0.615	V			
TJ	Range	- 55 to 175	°C			

VOLTAGE RATINGS VS-10UT10 PARAMETER SYMBOL **TEST CONDITIONS** UNITS VS-10WT10FN Maximum DC reverse voltage v V_R T_J = 25 °C 100

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current	I _{F(AV)}	50 % duty cycle at T_{C} = 159 °C, rectangular waveform		10	А
Maximum peak one cycle	I _{FSM}	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated	610	A
non-repetitive surge current		10 ms sine or 6 ms rect. pulse	$V_{\rm RRM}$ applied ⁽¹⁾	110	
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 3 A, L = 12 mH		54	mJ
Repetitive avalanche current	I _{AR}	Limited by frequency of operation and time pulse duration so that $T_J < T_J$ max. I_{AS} at T_J max. as a function of time pulse (see fig. 8)		I _{AS} at T _J max.	A

Note

⁽¹⁾ Measured connecting 2 anode pins

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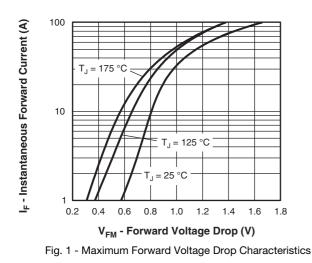
ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS		TYP.	MAX.	UNITS
		5 A	T _J = 25 °C	0.630	-	- V
		10 A		0.735	0.810	
Forward voltage drep	V _{FM} ⁽¹⁾⁽²⁾	20 A		0.840	0.890	
Forward voltage drop	V FM (1)(-)	5 A	T _J = 125 °C	0.530	-	
		10 A		0.615	0.660	
		20 A		0.730	0.770	
Reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C	V _R = Rated V _R	-	50	μA
		T _J = 125 °C		-	4	mA
Junction capacitance	CT	V_R = 5 V_{DC} (test signal range 100 kHz to 1 MHz), 25 °C		400	-	pF
Series inductance	L _S	Measured lead to lead 5 mm from package body		8.0	-	nH
Maximum voltage rate of change	dV/dt	Rated V _R		-	10 000	V/µs

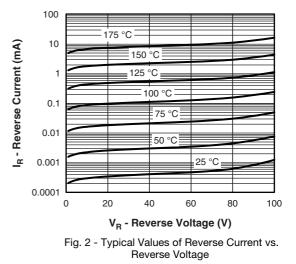
Notes

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

⁽²⁾ Only 1 anode pin connected

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		- 55 to 175	°C
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	2	°C/W
Typical thermal resistance, case to heatsink	R _{thCS}		0.3	C/W
Approvingete weight			0.3	g
Approximate weight			0.01	oz.
		Case style I-PAK	10U	T10
Marking device		Case style D-PAK	10WT10FN	





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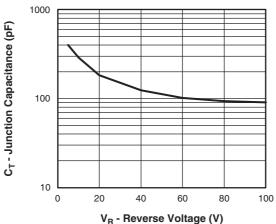


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

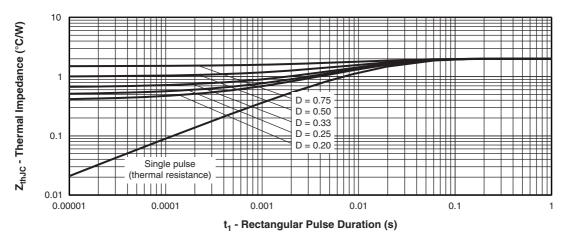


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

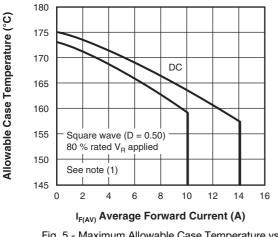
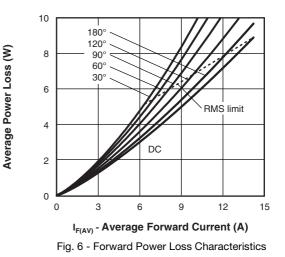


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current



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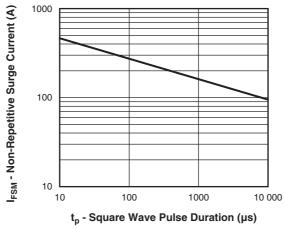
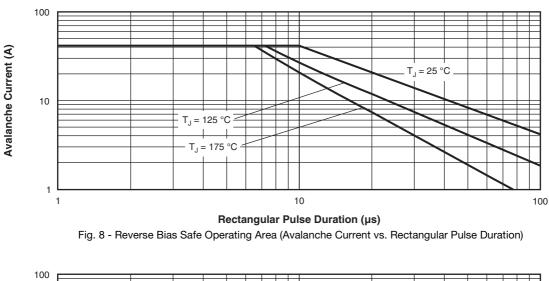


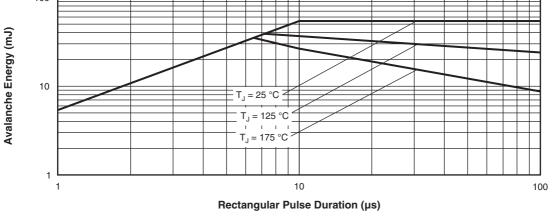
Fig. 7 - Maximum Non-Repetitive Surge Current

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{Forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see fig. 6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{Inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$







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VS-10UT10, VS-10WT10FN

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ORDERING INFORMATION TABLE

Device code VS-Т 10 **FN** 10 U TRL 2 1 3 (4)(5) 6 7 Vishay Semiconductors product 1 2 Current rating (10 A) 3 Package: • U = I-PAK • W = D-PAK T = Trench 4 5 Voltage code (100 V) 6 TO-252AA (D-PAK) 7 D-PAK, I-PAK: None = Tube (75 pieces) D-PAK only: • TR = Tape and reel

- TRL = Tape and reel (left oriented)
- TRR = Tape and reel (right oriented)

LINKS TO RELATED DOCUMENTS				
Dimensions	I-PAK (TO-251AA)	www.vishay.com/doc?95024		
Dimensions	D-PAK (TO-252AA)	www.vishay.com/doc?95448		
Part marking information	I-PAK (TO-251AA)	www.vishay.com/doc?95025		
	D-PAK (TO-252AA)	www.vishay.com/doc?95059		
Packaging information		www.vishay.com/doc?95033		
SPICE model		www.vishay.com/doc?95026		

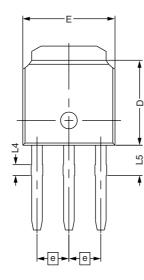


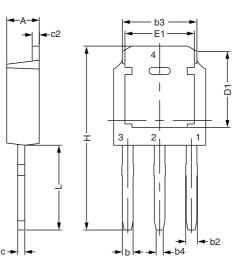
Outline Dimensions

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I-PAK - S

DIMENSIONS FOR I-PAK - S in millimeters





SYMBOL	DIMENSIONAL REQUIREMENTS				
STNIBOL	MIN.	NOM.	MAX.		
E	6.40	6.60	6.70		
L	3.98	4.13	4.28		
L4	0.66	0.76	0.86		
L5	1.96	2.16	2.36		
D	6.00	6.10	6.20		
Н	11.05	11.25	11.45		
b	0.64	0.76	0.88		
b2	0.77	0.84	1.14		
b3	5.21	5.34	5.46		
b4	0.41	0.51	0.61		
е	2.286 BSC				
A	2.20	2.30	2.38		
С	0.40	0.50	0.60		
c2	0.40	0.50	0.60		
D1	5.30	-	-		
E1	4.40	-	_		

Document Number: 95024 Revision: 24-May-11 For technical questions within your region, please contact one of the following: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u>

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